NSN 5961-01-032-4959

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Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Emitter

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

55.0 collector to base voltage, dc and 33.0 collector to emitter voltage, dc and 3.5 emitter to base voltage, dc

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0